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Post-synthetic halide conversion and selective halogen capture in hybrid perovskites†

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Reaction with halogen vapor allows us to post-synthetically exchange halides in both three- (3D) and two-dimensional (2D) organic–inorganic metal-halide perovskites. Films of 3D Pb–I perovskites cleanly convert to films of Pb–Br or Pb–Cl perovskites upon exposure to Br₂ or Cl₂ gas, respectively. This gas–solid reaction provides a simple method to produce the high-quality Pb–Br or Pb–Cl perovskite films required for optoelectronic applications. Reactivity with halogens can be extended to the organic layers in 2D metal-halide perovskites. Here, terminal alkene groups placed between the inorganic layers can capture Br₂ gas through chemisorption to form dibromoalkanes. This reaction's selectivity for Br₂ over I₂ allows us to scrub Br₂ to obtain high-purity I₂ gas streams. We also observe unusual halogen transfer between the inorganic and organic layers within a single perovskite structure. Remarkably, the perovskite's crystallinity is retained during these massive structural rearrangements.

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Introduction

We have investigated the post-synthetic reactivity of both organic and inorganic components in hybrid metal-halide perovskites. These hybrids combine the properties of molecules and extended solids, allowing for different reactivity to be realized in the same material. We have found that halogen gas can be used to cleanly exchange the halides in the inorganic framework, while preserving the perovskite's structure and crystallinity (Fig. 1). We used this reactivity to post-synthetically exchange the halides of the three-dimensional (3D) perovskites: (MA)[PbX₃] (MA = CH₃NH₃⁺, X = Br, and I). The Pb–I perovskite has recently emerged as a promising absorber for high-efficiency and low-cost solar cells.^{1,2} With a bandgap of 1.6 eV,³ these absorbers have so far yielded solar cells with voltages up to 1.15 V.⁴ Halide substitution in this structure affords bandgaps of 3.11 and 2.35 eV for X = Cl⁵ and Br,⁵ respectively, while mixed-halide perovskites show systematic shifts in bandgap with halide ratio.⁶ This electronic flexibility has enabled further applications in wavelength-tunable light-emitting diodes^{7,8} and lasers^{9,10} using Pb–Br and Pb–Cl perovskites. In order to access higher voltages for solar cells, and for the construction of the higher bandgap absorber in a tandem solar cell, there is considerable interest in (MA)[PbBr₃] absorbers.¹¹ These optoelectronic devices require uniform films with good substrate

coverage. Such high-quality films of (MA)[PbI₃] can be formed by many methods, including depositing (MA)I with either PbI₂ or PbCl₂ precursors or by converting PbI₂ films to the perovskite through exposure to (MA)I solution or vapor.^{2,12} However, similar processing does not yield continuous films of (MA)[PbBr₃] and (MA)[PbCl₃]. We find that by using Pb–I films as templates, conversion reactions with Br₂ and Cl₂ gas afford uniform and high-coverage films of Pb–Br and Pb–Cl perovskites, respectively, while generating only volatile by-products. Because different routes to forming high-coverage Pb–I films on various substrates have already been developed, converting these films to (MA)[PbX₃] (X = Br and Cl) using halogen vapor

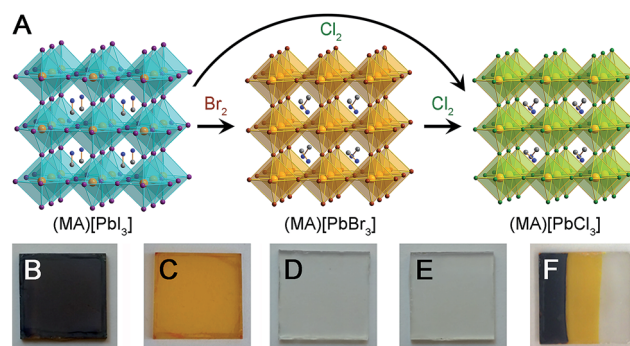


Fig. 1 (A) Reaction of 3D perovskites (MA)[PbX₃] (MA = CH₃NH₃⁺, X = I and Br) with Br₂ and Cl₂ gas. Pb: orange, I: purple, Br: brown, Cl: green, N: blue, C: gray. Photographs of (B) a (MA)[PbI₃] film, (C) a (MA)[PbBr₃] film prepared by exposing a (MA)[PbI₃] film to Br₂ gas, (D) a (MA)[PbCl₃] film prepared by sequentially exposing a (MA)[PbI₃] film to Br₂ and Cl₂ gas, and (E) a (MA)[PbCl₃] film prepared by exposing a (MA)[PbI₃] film to Cl₂ gas. (F) A film of all three perovskites formed by exposing parts of a (MA)[PbI₃] film to Br₂ and then to Cl₂ using a mask.

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provides a very general method for obtaining the high-quality Pb–Br and Pb–Cl perovskite films required for optoelectronic devices.

This reactivity with halogens can be extended to the organic groups in 2D hybrid perovskites. We recently described reversible and irreversible I₂ capture in the organic layers of 2D perovskites.¹³ These nonporous materials topotactically expand, by up to 36% in volume, to capture iodine gas by forming covalent C–I bonds in the organic layers. Most porous sorbents capture gases through physisorption, where selectivity is achieved through pore size or by weak electrostatic interactions.^{14,15} A less explored alternative is chemisorption in nonporous solids, where chemical reactivity dictates substrate selectivity. Here, we report on selective chemisorption of Br₂ and IBr over I₂ in 2D perovskites. This selectivity can be used to scrub Br₂ and IBr to obtain high-purity I₂ gas streams—a separation that is difficult to achieve in the gas phase. Furthermore, perovskites that react with halogens in both the inorganic and organic layers show unusual halogen transfer between the inorganic and organic layers of the same 2D perovskite. Notably, the materials remain crystalline despite these very large atomic rearrangements.

Experimental section

Aqueous solutions were prepared using deionized water. Organic solvents were of reagent grade or higher purity and were not dried prior to use except for *N,N*-dimethylformamide (DMF), which was dried and degassed using a JC Meyer solvent purification system. The 2D perovskites (BEA)₂[PbBr₄] and (PEA)₂[CuCl₄] (BEA = but-3-en-1-ammonium and PEA = prop-2-en-1-ammonium) were synthesized according to our previous report.¹³ All other reagents were purchased from commercial vendors and used as received. Prior to the halogenation reactions, the 2D perovskites were ball-milled for 3 h at 500 rpm in 12 mL zirconia vials equipped with 5 mm agate balls using a Fritsch Pulverisette 7 planetary mill.

Preparation of (MA)[PbI₃] films

Solid PbI₂ (230 mg, 0.500 mmol) was dissolved in 1 mL of dry DMF. After filtering through paper, the solution (60 μL) was deposited on a clean fluorine-doped tin oxide (FTO) coated glass substrate and spun at 2000 rpm for 30 s. Immediately after spinning began, a light flow of nitrogen was directed at the substrate to aid the formation of a flat, uniform film. A dry isopropanol solution of (CH₃NH₃)I ((MA)I, 63.0 mM) was added dropwise to the PbI₂ film spun at 3000 rpm (approx. 200 μL, 8 drops). The sample was allowed to dry between each drop to avoid material loss from the spinning substrate. The films were then annealed at 100 °C for 15 minutes. The phase purity of the (MA)[PbI₃] films was confirmed by powder X-ray diffraction (PXRD) (Fig. S1†) and the film coverage was determined through scanning electron microscopy (Fig. 2A).

Conversion of (MA)[PbI₃] to (MA)[PbBr₃] using Br₂ gas

Liquid bromine (ca. 3 mL) was added to a 50 mL round-bottom flask. A gas-flow meter was used to allow 20 μL min^{−1} of dry N₂

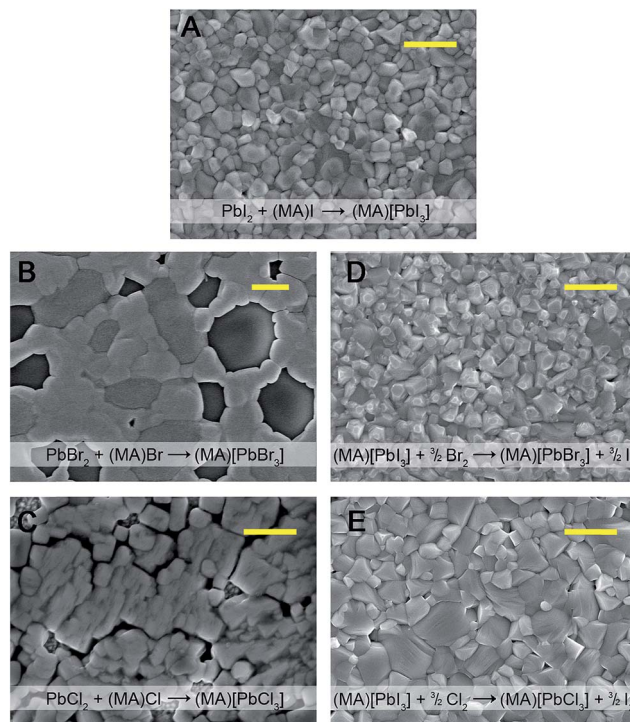


Fig. 2 SEM images of 3D perovskite films. Films prepared from PbX₂ and (MA)X solutions (X = I, Br, or Cl): (A) (MA)[PbI₃], (B) (MA)[PbBr₃], and (C) (MA)[PbCl₃]. Films formed by reaction of (MA)[PbI₃] films with X₂ gas (X = Br or Cl): (D) (MA)[PbBr₃] and (E) (MA)[PbCl₃]. The yellow scale bar shows 1 μm.

carrier gas to flow over the Br₂ vapor. This gas stream was combined with a dry N₂ stream (flow rate of 8 mL min^{−1}), creating a dilution of ca. 400 times that of saturated Br₂ vapor. This diluted Br₂ vapor was then passed over a (MA)[PbI₃] film for 8 minutes, converting the film into an orange/yellow (MA)[PbBr₃] film. The phase purity of the (MA)[PbBr₃] film was confirmed by PXRD (Fig. S2 and S3†) and the film coverage was determined through scanning electron microscopy (Fig. 2D).

Conversion of (MA)[PbX₃] (X = I or Br) to (MA)[PbCl₃] using Cl₂ gas

Pure Cl₂ gas (flow rate of 20 μL min^{−1}) was combined with dry N₂ (flow rate of 10 mL min^{−1}) to dilute the Cl₂ by a factor of 500. This diluted gas stream was then passed over a (MA)[PbX₃] (X = I or Br) film for 5 minutes, converting the film to a colorless (MA)[PbCl₃] film. The phase purity of the (MA)[PbCl₃] film was confirmed by PXRD (Fig. S3 and S4†) and the film coverage was determined through scanning electron microscopy (Fig. 2E).

Bromination of 2D perovskites

Perovskite powder samples (2–100 mg) were placed in a darkened glass jar containing approximately 0.5 g of liquid Br₂, and the jar was closed with a PTFE-lined cap. The samples were placed in glass vials to avoid contact between the solids and liquid Br₂. After reaction with Br₂ (over 12–48 h), the solids were held at reduced pressure for 0.5 h to remove surface-adsorbed



bromine and analyzed by PXRD (Fig. S5 and S6†) and solid-state IR spectroscopy (Fig. S7 and S8†).

Chlorination of 2D perovskites

Perovskite powder samples (2–100 mg) were placed in a gas-tight glass chamber and evacuated for approximately 10 minutes. The chamber was then filled with Cl_2 gas at 1 atm, sealed, and placed in the dark for 12–48 h. After reaction with Cl_2 , the solids were held at reduced pressure for 0.5 h and analyzed by PXRD (Fig. S9–S11†) and solid-state IR spectroscopy (Fig. S12†).

Results and discussion

Post-synthetic halide conversion in 3D perovskites

Thin-film solar cells require absorbers of uniform thickness and good substrate coverage in order to maximize light absorption and avoid electrical shunts. Owing to its higher bandgap, compared to that of the Pb–I perovskite, the Pb–Br perovskite has been targeted as an absorber for higher voltage solar cells and as the higher-bandgap absorber in a tandem device. However, the typical deposition methods used for Pb–I perovskites^{2,12} do not afford high-quality Pb–Br perovskite films. For example, codeposition of PbBr_2 and $(\text{MA})\text{Br}$ from *N,N*-dimethylformamide leads to discontinuous films of $(\text{MA})[\text{PbBr}_3]$ (Fig. 2B). Indeed, the low short-circuit current attained from devices containing these absorbers has been attributed to poor perovskite film uniformity.¹¹ The film quality and device performance have been improved by incorporating chloride¹⁶ or HBr ¹⁷ to the precursor solutions and solar cells with $(\text{MA})[\text{PbBr}_3]$ absorbers have shown high open-circuit voltages (V_{OC}) of up to 1.51 V.¹⁷ We investigated if exposing high-coverage Pb–I perovskite films to halogen vapor could provide a general method for easily obtaining the high-quality $(\text{MA})[\text{PbX}_3]$ ($\text{X} = \text{Br}$ and Cl) films that are required for photovoltaic and other optoelectronic devices such as light-emitting diodes^{7,8} and lasers.^{9,10}

Dark red/brown films of $(\text{MA})[\text{PbI}_3]$ (Fig. 1B) turn orange when exposed to Br_2 vapor (Fig. 1C) and the powder X-ray diffraction (PXRD) pattern of the product confirms complete conversion to $(\text{MA})[\text{PbBr}_3]$ (Fig. S2 and S3†). Similarly, $(\text{MA})[\text{PbI}_3]$ films turn colourless when exposed to Cl_2 gas (Fig. 1E) and PXRD data confirm quantitative formation of $(\text{MA})[\text{PbCl}_3]$ (Fig. S3 and S4†). Notably, films of $(\text{MA})[\text{PbX}_3]$ ($\text{X} = \text{Br}$ or Cl) formed through this conversion process (and without subsequent annealing) are consistently more crystalline than the parent films of annealed $(\text{MA})[\text{PbI}_3]$ (Fig. S1†). Films of $(\text{MA})[\text{PbBr}_3]$ can also be cleanly converted to $(\text{MA})[\text{PbCl}_3]$ films through reaction with Cl_2 gas (Fig. 1D and S4†). These transformations occur in a few seconds with pure halogen vapor (see Video in the ESI†). Dilute halogen gas streams produce higher-quality films of the product (Fig. 2D and E). Importantly, the films of $(\text{MA})[\text{PbCl}_3]$ and $(\text{MA})[\text{PbBr}_3]$ that are formed through reaction with dilute halogen vapor are consistently more uniform and have higher substrate coverage than films produced through sequential deposition or codeposition of PbX_2 and $(\text{MA})\text{X}$ ($\text{X} = \text{Cl}$ or Br) (Fig. 2B and C). By using a simple

mask, we can also convert parts of a $(\text{MA})[\text{PbI}_3]$ film to $(\text{MA})[\text{PbBr}_3]$ and then to $(\text{MA})[\text{PbCl}_3]$ by sequentially exposing unmasked areas to Br_2 and Cl_2 vapor (Fig. 1F).

These conversion reactions could be understood in terms of halogen reduction potentials. Standard reduction potentials for I_2 , Br_2 , and Cl_2 are 0.54, 1.07, and 1.36 V vs. SHE, respectively.¹⁸ Therefore, Br_2 gas can oxidize the I^- ions in the inorganic sheets to I_2 , while generating Br^- ions that coordinate to the Pb^{2+} centers, thereby transforming $(\text{MA})[\text{PbI}_3]$ to $(\text{MA})[\text{PbBr}_3]$. Similarly, Cl_2 gas can oxidize either I^- or Br^- to form the halogen, and cleanly convert $(\text{MA})[\text{PbI}_3]$ or $(\text{MA})[\text{PbBr}_3]$ to $(\text{MA})[\text{PbCl}_3]$ with only gas-phase by-products.

Bromine capture in 2D perovskites

Similar to the reactivity we observed with I_2 gas,¹³ exposing the 2D alkene perovskite $(\text{BEA})_2[\text{PbBr}_4]$ ($\text{BEA} = \text{but-3-en-1-ammonium}$, Fig. 3B and 4) to Br_2 gas results in a new crystalline phase with an extended crystallographic c axis. Unlike I_2 absorption, however, Br_2 absorption is irreversible owing to the greater stability of the dibromo-alkane compared to the diiodo-alkane. We confirmed the formation of BEA-Br_2 within the hybrid perovskite first by solid-state vibrational spectroscopy and then by solution-state NMR spectroscopy and mass spectrometry of the digested material (Fig. S7 and S13†). We also obtained single crystals of the product $(\text{BEA-Br}_2)_2[\text{PbBr}_4]$ (Fig. 3A) by allowing a concentrated solution of $(\text{BEA-Br}_2)_2[\text{PbBr}_4]$ in aqueous HBr to evaporate over 5 days. The crystal structure¹⁹ confirms that the transformation occurs as a topotactic expansion of the inorganic layers as Br_2 adds across the terminal alkenes. Here, the c axis expands by 3.2 Å (23.9%) and the unit-cell volume increases by 204 Å³ (22.5%) (Table 1). The $\text{C}=\text{C}$ bond lengths (1.306(1) and 1.303(1) Å) in $(\text{BEA})_2[\text{PbBr}_4]$ elongate to form the single $\text{C}-\text{C}$ bonds in $(\text{BEA-Br}_2)_2[\text{PbBr}_4]$ (1.456(1) and 1.462(1) Å). The organo-bromine atoms in $(\text{BEA-Br}_2)_2[\text{PbBr}_4]$ form one-dimensional chains that traverse the material with $\text{Br}\cdots\text{Br}$ contacts of 3.645(1) Å. We were previously unable to obtain the crystal structure of $(\text{BEA-I}_2)_2[\text{PbBr}_4]$ due to its instability to I_2 release.¹³ The close match between its PXRD pattern and the PXRD pattern predicted from the crystal structure of $(\text{BEA-Br}_2)_2[\text{PbBr}_4]$ confirms that very similar structures are formed in both cases (Fig. S14†). The reactivity of $(\text{BEA})_2[\text{PbBr}_4]$ with Br_2 can be extended to hybrid perovskites containing different metals, halides, and alkenes. For example, $(\text{PEA})_2[\text{CuCl}_4]$ ($\text{PEA} = \text{prop-2-en-1-ammonium}$) reacts with Br_2 gas to form $(\text{PEA-Br}_2)_2[\text{CuCl}_4]$, as corroborated through single-crystal and PXRD data (Fig. S6 and S15†).

Br_2 and IBr scrubbing

Reversible I_2 absorption and irreversible Br_2 absorption by $(\text{BEA})_2[\text{PbBr}_4]$ prompted us to study the perovskite's utility for scrubbing Br_2 from I_2 gas streams. This separation is traditionally performed by reducing the halogens and selectively precipitating their halide salts.³ However, this process is labor and energy intensive, especially if the halogen and not the halide is the desired product. This gas-phase separation is further complicated because I_2 and Br_2 coexist in equilibrium



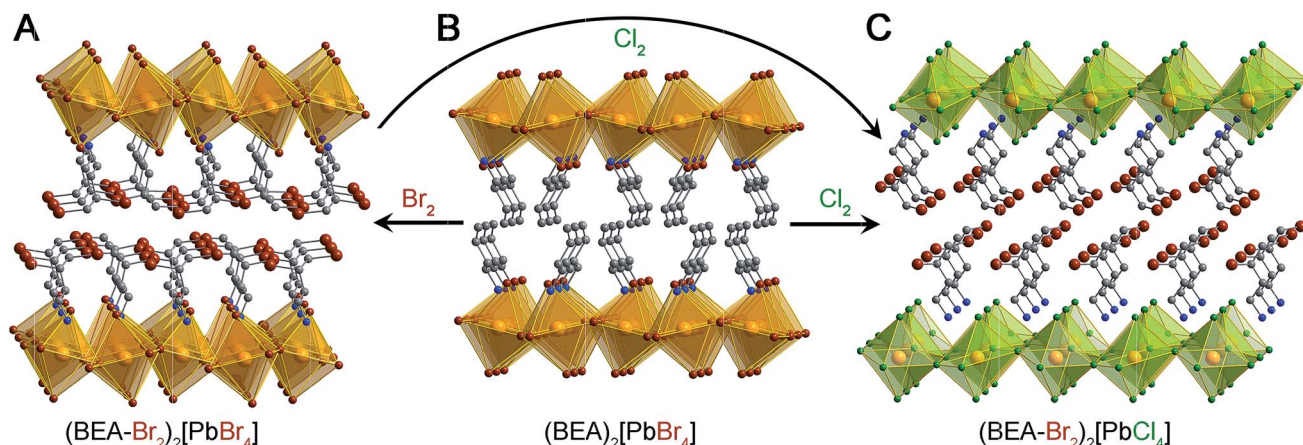


Fig. 3 Reaction of (BEA)₂[PbBr₄] with Br₂ and Cl₂ gas. Crystal structures of (A) (BEA-Br₂)₂[PbBr₄], (B) (BEA)₂[PbBr₄], and (C) (BEA-Br₂)₂[PbCl₄]. Pb-Br octahedra: orange, Pb-Cl octahedra: green, Pb: orange, Br: brown, Cl: green, N: blue, C: gray. Hydrogen and disordered atoms are omitted for clarity.¹⁹

with their reaction product IBR.²⁰ We reasoned that irreversible Br₂ addition to (BEA)₂[PbBr₄] should shift the gas-phase equilibrium towards I₂, thereby removing Br₂ and IBR from the gas-phase mixture (Fig. 5).

To test its capacity for I₂-Br₂ separation, we exposed solid (BEA)₂[PbBr₄] to 1 : 1 and 2 : 1 mole ratios of I₂-Br₂ gas. Analysis of the resulting products by mass spectrometry and NMR showed the presence of (BEA-Br₂)₂[PbBr₄] and trace amounts of (BEA-IBr)₂[PbBr₄] (BEA-IBr = 3-bromo-4-iodobutan-1-ammonium and 4-bromo-3-iodobutan-1-ammonium). We obtained average values of 87(2)% and 86(4)% for the total Br₂ recovered as (BEA-Br₂)₂[PbBr₄] for the 2 : 1 and 1 : 1 mixtures, respectively

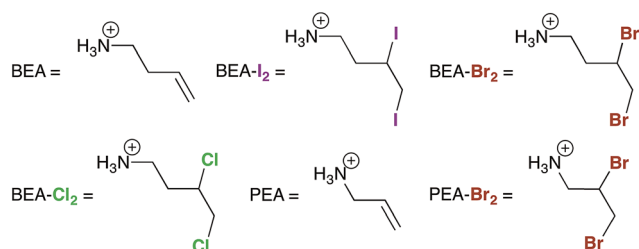


Fig. 4 Abbreviations used for the organic cations in the 2D perovskites.

Table 1 Unit-cell parameters for (BEA)₂[PbBr₄] and (BEA-Br₂)₂[PbBr₄]

	(BEA) ₂ [PbBr ₄] ^a	(BEA-Br ₂) ₂ [PbBr ₄]	Difference
<i>a</i> (Å)	8.208(1)	7.973(1)	−0.23
<i>b</i> (Å)	8.204(1)	8.388(1)	0.18
<i>c</i> (Å)	13.543(1)	16.775(2)	3.23
<i>α</i> (°)	96.22(1)	95.61(1)	−0.61
<i>β</i> (°)	90	95.89(1)	5.89
<i>γ</i> (°)	90	90.37(1)	0.37
Volume (Å ³)	906.5(1)	1110.5(1)	204

^a The unit cell was reoriented for ease of comparison.

(Table S1†). This results in a final Br₂ concentration of less than 20 ppm in the gas phase. We note that Br₂ adsorption to the container walls and small losses during transfer results in an underestimation of the total captured Br₂. This separation cannot easily be performed using the alkene molecules alone. The alkyl amines are liquids and the chloride salts of the alkene-ammonium molecules deliquesce under the same conditions used for I₂-Br₂ separation with the perovskites. These results illustrate that chemisorption in nonporous materials can be used to separate molecules of similar size.

Chlorine capture in 2D perovskites

Exposure of (BEA)₂[PbBr₄] to Cl₂ gas also afforded a new crystalline phase. However, analysis of the digested product by mass spectrometry revealed that the reaction product contained BEA-Br₂ and not BEA-Cl₂. The PXRD pattern of the reaction product with Cl₂ matches that of the Pb-Cl perovskite (BEA-Br₂)₂[PbCl₄] (Fig. 3C and S9†), indicating that chloride was incorporated into the inorganic layers. This transformation could occur as a multi-step process. The Br[−] ions in the inorganic layers could first be oxidized by Cl₂ to form Br₂ and Cl[−] ions. The Cl[−] ions could then be incorporated into the inorganic sheets while Br₂ molecules add across the double bonds of the alkenes, thereby facilitating halogen transfer between the inorganic and organic layers. Trapping of the Br₂ molecules,

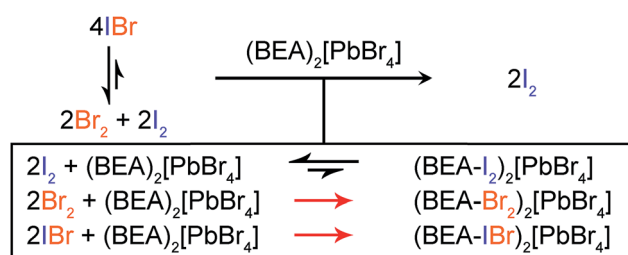


Fig. 5 Schematic representation for Br₂ and IBR scrubbing from I₂ gas streams using (BEA)₂[PbBr₄].

generated during halogen conversion in the inorganic sheets, by the terminal alkenes supports our proposed mechanism for halide conversion in 3D perovskites. Interestingly, this transformation also occurs with retention of crystallinity (Fig. S10†). We obtained the crystal structure of $(\text{BEA-Cl}_2)_2[\text{PbBr}_4]$ (formed through reaction of $(\text{BEA-Cl}_2)\text{Br}$ and PbBr_2 , Fig. S16†) to confirm that it is a stable, isolable material, though we do not see it in the reaction product of $(\text{BEA})_2[\text{PbBr}_4]$ and Cl_2 gas. We also determined that unsaturated organic groups were not required for this halide conversion. For example, exposure of $(\text{BEA-Br}_2)_2[\text{PbBr}_4]$ to Cl_2 gas resulted in its conversion to $(\text{BEA-Br}_2)_2[\text{PbCl}_4]$ (Fig. 3 and S11†).

Terminal alkenes can react with both Cl_2 and Br_2 to form dihalo-alkanes. The absence of BEA-Cl_2 in the alkene perovskite after exposure to Cl_2 can be understood in terms of reaction kinetics, and is consistent with experimental rates of alkene chlorination and bromination in solution.^{21–23} Computational studies on the relative stabilities of the halonium ions^{24–26} have attributed the faster rates of alkene bromination to the greater stability of the bromonium intermediate compared to the chloronium intermediate. Therefore, although C–Cl bond enthalpies (*ca.* 85 kcal mol^{−1}) are greater than C–Br bond enthalpies (*ca.* 72 kcal mol^{−1}),²⁷ the kinetics of alkene halogenation and the redox chemistry that occurs in the perovskite allows us to exclusively isolate BEA-Br_2 between the inorganic sheets. Therefore, $(\text{BEA})_2[\text{PbBr}_4]$ can be used to capture both Br_2 and Cl_2 gas. Here, Cl_2 is trapped in the inorganic sheets, while Br_2 is trapped in the organic layers.

Conclusions

We show that halogen gas can be used to exchange the halides in the inorganic components of hybrid perovskites while generating only gaseous by-products. For this conversion to occur, the halogen gas must have a more positive reduction potential than the halide in the perovskite. This reaction provides a convenient method of converting 3D Pb–I perovskite films to Pb–Br or Pb–Cl perovskite films of high quality, without further annealing or purification steps. The ability to post-synthetically exchange halides in hybrid perovskites using redox chemistry, while preserving the crystalline structure, is a testament to their remarkable self-annealing properties. Recently, halides in hybrid perovskites have been exchanged by immersing a perovskite film in a solution containing an excess of a halide salt,²⁸ although this method does not appear to preserve film morphology. We further show that the organic functionalities in 2D perovskites can be designed for selective chemisorption to enable separation of gases of similar size. In further studies, we will attempt to tune these sorbents for timed-release of the substrate to inexpensively regenerate the capture material. In future work we will also investigate partially converting the halides in 3D perovskite films as a function of film depth. Because the Pb–Br and Pb–Cl perovskites are more moisture resistant than the Pb–I perovskite, a thin but continuous top layer of the Pb–Br/Cl perovskite may protect the underlying Pb–I absorber from moisture. The long-term stability, under device operating conditions, of perovskite films

containing these stratified halide compositions requires further study. We recently described instabilities in the homogenous mixed-halide perovskites $(\text{MA})[\text{Pb}(\text{Br}_x\text{I}_{1-x})_3]$ that led to the reversible formation of trap states under continuous white-light illumination.²⁹ The ability to partially convert only the top of a Pb–I perovskite film to a Pb–Br perovskite may also aid carrier extraction in perovskite solar cells. Because the halide composition predominantly affects the top of the valence band, a stable halide gradient at the Pb–I/Pb–Br interface could help shuttle holes to the cathode (Fig. S17†).

Acknowledgements

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